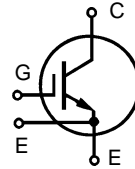


# High Voltage IGBT

## IXDN 75N120

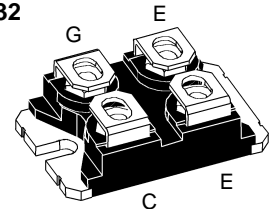
$V_{CES} = 1200\text{ V}$   
 $I_{C25} = 150\text{ A}$   
 $V_{CE(sat) typ} = 2.2\text{ V}$

Short Circuit SOA Capability  
Square RBSOA



miniBLOC, SOT-227 B

E153432



E = Emitter ①, C = Collector  
G = Gate, E = Emitter ①

① Either Emitter terminal can be used as Main or Kelvin Emitter

| Symbol                                 | Conditions   | Maximum Ratings                       |                  |
|--|--|---------------------------------------|------------------|
| $V_{CES}$                              | $T_J = 25^\circ\text{C to } 150^\circ\text{C}$   | 1200                                  | V                |
| $V_{CGR}$                              | $T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 20\text{ k}\Omega$   | 1200                                  | V                |
| $V_{GES}$                              | Continuous   | $\pm 20$                              | V                |
| $V_{GEM}$                              | Transient  | $\pm 30$                              | V                |
| $I_{C25}$                              | $T_C = 25^\circ\text{C}$   | 150                                   | A                |
| $I_{C90}$                              | $T_C = 90^\circ\text{C}$   | 95                                    | A                |
| $I_{CM}$                               | $T_C = 90^\circ\text{C}, t_p = 1\text{ ms}$  | 190                                   | A                |
| <b>RBSOA</b>                           | $V_{GE} = \pm 15\text{ V}, T_J = 125^\circ\text{C}, R_G = 15\ \Omega$<br>Clamped inductive load, $L = 30\ \mu\text{H}$ | $I_{CM} = 150$<br>$V_{CEK} < V_{CES}$ | A                |
| <b><math>t_{SC}</math><br/>(SCSOA)</b> | $V_{GE} = \pm 15\text{ V}, V_{CE} = V_{CES}, T_J = 125^\circ\text{C}$<br>$R_G = 15\ \Omega$ , non repetitive           | 10                                    | $\mu\text{s}$    |
| $P_C$                                  | $T_C = 25^\circ\text{C}$ IGBT  | 660                                   | W                |
| $V_{ISOL}$                             | 50/60 Hz; $I_{ISOL} \leq 1\text{ mA}$  | 2500                                  | V~               |
| $T_J$                                  |  | -40 ... +150                          | $^\circ\text{C}$ |
| $T_{stg}$                              |  | -40 ... +150                          | $^\circ\text{C}$ |
| $M_d$                                  | Mounting torque  | 1.5/13                                | Nm/lb.in.        |
|  | Terminal connection torque (M4)  | 1.5/13                                | Nm/lb.in.        |
| <b>Weight</b>                          |  | 30                                    | g                |

### Features

- NPT IGBT technology
- low saturation voltage
- low switching losses
- square RBSOA, no latch up
- high short circuit capability
- positive temperature coefficient for easy paralleling
- MOS input, voltage controlled
- International standard package miniBLOC

### Advantages

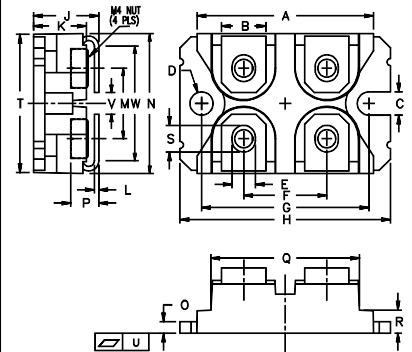
- Space savings
- Easy to mount with 2 screws
- High power density

### Typical Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

| Symbol        | Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                     |
|---------------|---|---|------|---------------------|
|               |   | min.  | typ. | max.                |
| $V_{(BR)CES}$ | $V_{GE} = 0\text{ V}$   | 1200  |      | V                   |
| $V_{GE(th)}$  | $I_C = 3\text{ mA}, V_{CE} = V_{GE}$  | 4.5   |      | 6.5 V               |
| $I_{CES}$     | $V_{CE} = V_{CES}$<br>$T_J = 25^\circ\text{C}$<br>$T_J = 125^\circ\text{C}$ |   | 6    | 4 mA<br>mA          |
| $I_{GES}$     | $V_{CE} = 0\text{ V}, V_{GE} = \pm 20\text{ V}$                             |   |      | $\pm 500\text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = 75\text{ A}, V_{GE} = 15\text{ V}$                                   | 2.2   | 2.7  | V                   |

| Symbol       | Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |          |
|--------------|--|---|------|----------|
|              |  | min.  | typ. | max.     |
| $C_{ies}$    | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$  |   | 5500 | pF       |
| $C_{oes}$    |  |   | 750  | pF       |
| $C_{res}$    |  |   | 330  | pF       |
| $Q_g$        | $I_C = 75\text{ A}, V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$  |   | 360  | nC       |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = 75\text{ A}, V_{GE} = \pm 15\text{ V},$<br>$V_{CE} = 600\text{ V}, R_G = 15\ \Omega$ |   | 100  | ns       |
| $t_r$        |  |   | 50   | ns       |
| $t_{d(off)}$ |  |   | 650  | ns       |
| $t_f$        |  |   | 50   | ns       |
| $E_{on}$     |  |   | 12.1 | mJ       |
| $E_{off}$    |  | 10.5  | mJ   |          |
| $R_{thJC}$   | Package with heatsink compound   |   | 0.1  | 0.19 K/W |
| $R_{thCK}$   |  |   |      | K/W      |

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M4 screws (4x) supplied

| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 31.50      | 31.88 | 1.240  | 1.255 |
| B    | 7.80       | 8.20  | 0.307  | 0.323 |
| C    | 4.09       | 4.29  | 0.161  | 0.169 |
| D    | 4.09       | 4.29  | 0.161  | 0.169 |
| E    | 4.09       | 4.29  | 0.161  | 0.169 |
| F    | 14.91      | 15.11 | 0.587  | 0.595 |
| G    | 30.12      | 30.30 | 1.186  | 1.193 |
| H    | 37.80      | 38.20 | 1.489  | 1.505 |
| J    | 11.68      | 12.22 | 0.460  | 0.481 |
| K    | 8.92       | 9.60  | 0.351  | 0.378 |
| L    | 0.76       | 0.84  | 0.030  | 0.033 |
| M    | 12.60      | 12.85 | 0.496  | 0.506 |
| N    | 25.15      | 25.42 | 0.990  | 1.001 |
| O    | 1.98       | 2.13  | 0.078  | 0.084 |
| P    | 4.95       | 5.97  | 0.195  | 0.235 |
| Q    | 26.54      | 26.90 | 1.045  | 1.059 |
| R    | 3.94       | 4.42  | 0.155  | 0.174 |
| S    | 4.72       | 4.85  | 0.186  | 0.191 |
| T    | 24.59      | 25.07 | 0.968  | 0.987 |
| U    | -0.05      | 0.1   | -0.002 | 0.004 |
| V    | 3.30       | 4.57  | 0.130  | 0.180 |
| W    | 0.780      | 0.830 | 0.031  | 0.033 |

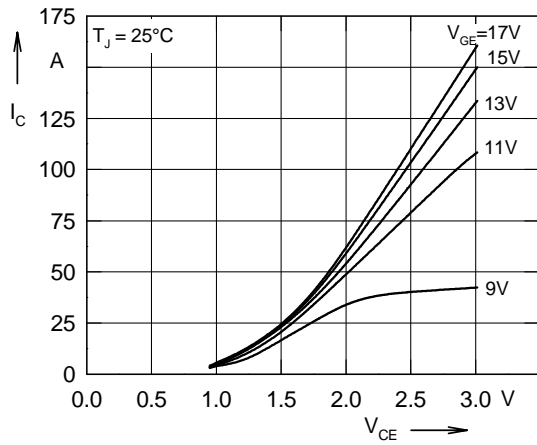


Fig. 1 Typ. output characteristics

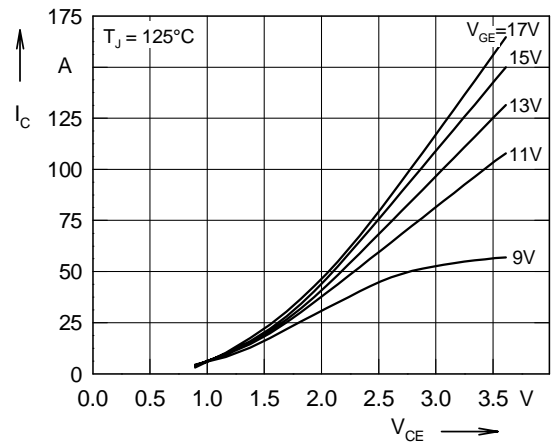


Fig. 2 Typ. output characteristics

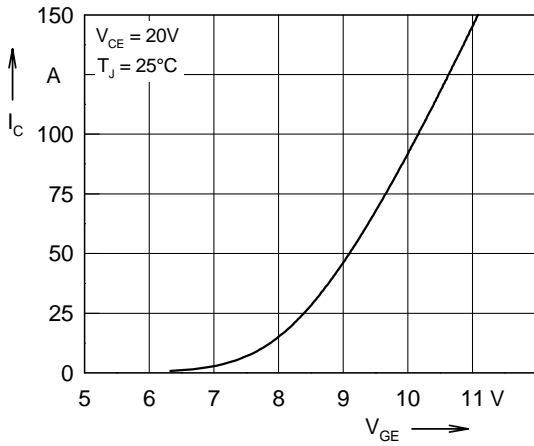


Fig. 3 Typ. transfer characteristics

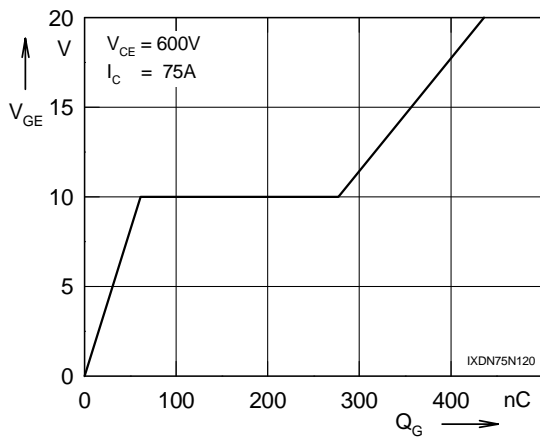


Fig. 4 Typ. turn on gate charge

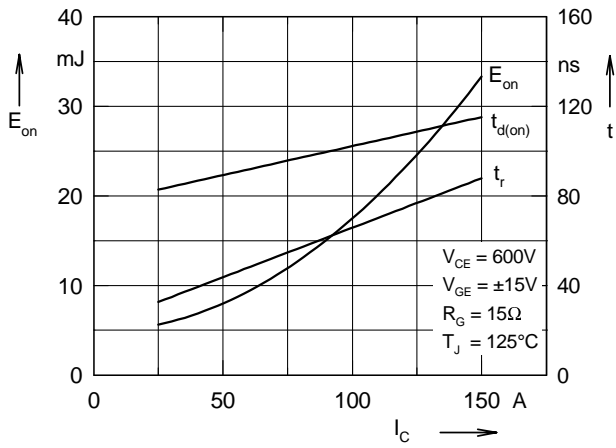


Fig. 5 Typ. turn on energy and switching times versus collector current

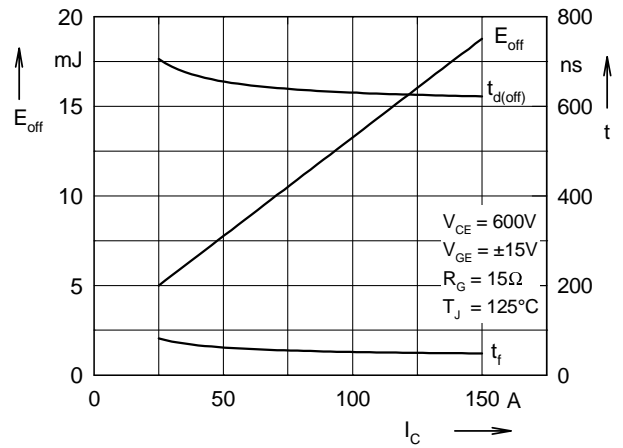


Fig. 6 Typ. turn off energy and switching times versus collector current

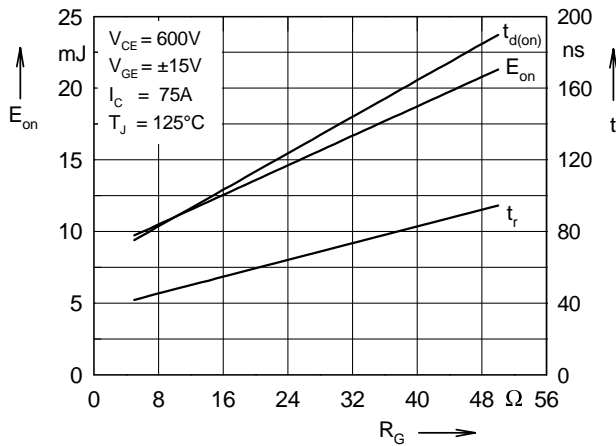


Fig. 7 Typ. turn on energy and switching times versus gate resistor

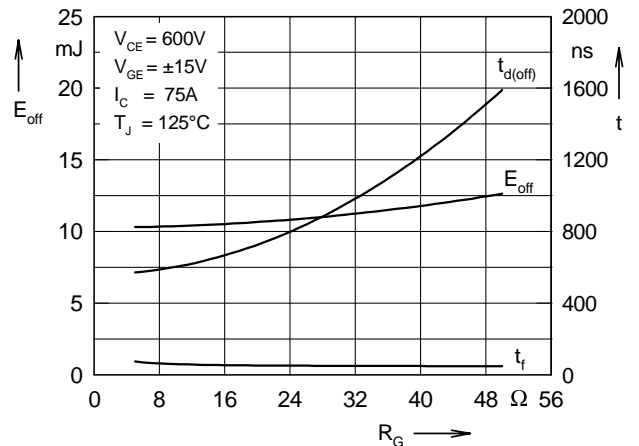


Fig.8 Typ. turn off energy and switching times versus gate resistor

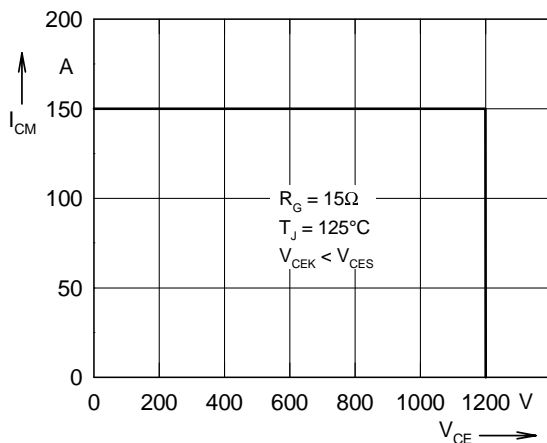


Fig. 9 Reverse biased safe operating area RBSOA

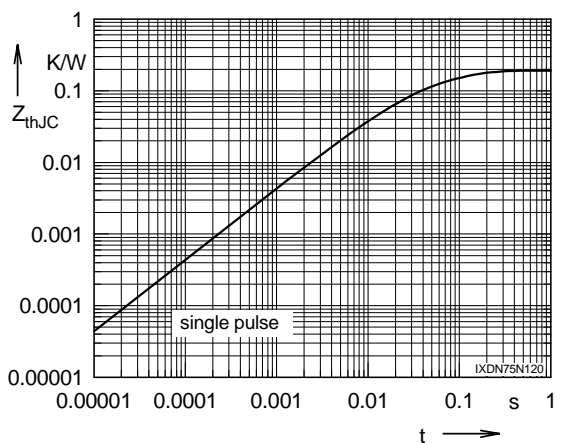


Fig. 10 Typ. transient thermal impedance